



# HMC-C038

## WIDEBAND DRIVER AMPLIFIER MODULE, 2 - 35 GHz

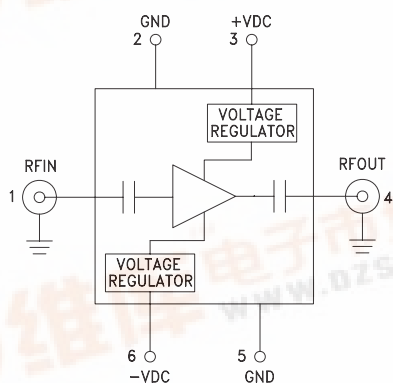


### Typical Applications

The HMC-C038 Wideband Driver is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation
- Fiber Optics

### Functional Diagram



### Features

- Gain: 12 dB @ 10 GHz
- P1dB Output Power: +18 dBm @ 10 GHz
- Regulated Supply and Bias Sequencing
- Hermetically Sealed Module
- Field Replaceable 2.92 mm Connectors
- 55 to +85°C Operating Temperature

### General Description

The HMC-C038 is a GaAs PHEMT MMIC Distributed Power Amplifier in a miniature, hermetic module with replaceable 2.92mm connectors which operates between 2 and 35 GHz. The amplifier provides 12 dB of gain, +29 dBm output IP3 and up to +18 dBm of output power at 1 dB gain compression. Gain flatness is excellent from 2 - 16 GHz making the HMC-C038 ideal for EW, ECM RADAR and test equipment applications. The wideband amplifier I/Os are internally matched to 50 Ohms and are DC blocked. Integrated voltage regulators allow for flexible biasing of both the negative and positive supply pins, while internal bias sequencing circuitry assures robust operation.

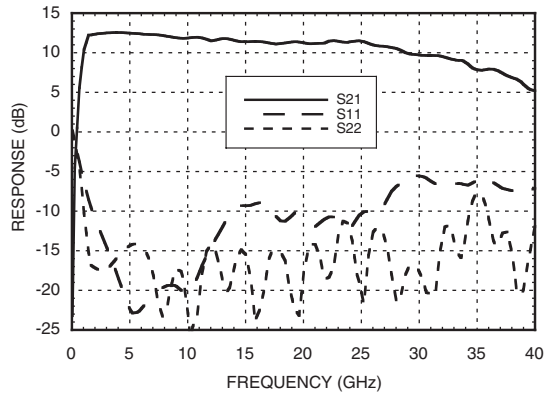
### Electrical Specifications, $T_A = +25^\circ C$ , +VDC = +11V to +16V, -VDC = -4V to -12V

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range		2 - 15		15 - 27			27 - 35			GHz
Gain	9	12		8	11		6	9		dB
Gain Flatness		±0.5			±0.4			±1.5		dB
Gain Variation Over Temperature		0.02	0.03		0.02	0.03		0.02	0.03	dB/°C
Noise Figure		3.0			4.0			6.0		dB
Input Return Loss		15			10			6		dB
Output Return Loss		15			13			13		dB
Output Power for 1 dB Compression (P1dB)	15	18		13	16		10	14		dBm
Saturated Output Power (Psat)		20			18.5			15.5		dBm
Output Third Order Intercept (IP3)		29			26			25		dBm
Positive Supply Current (+IDC)		92			92			92		mA
Negative Supply Current (-IDC)		5.3			5.3			5.3		mA

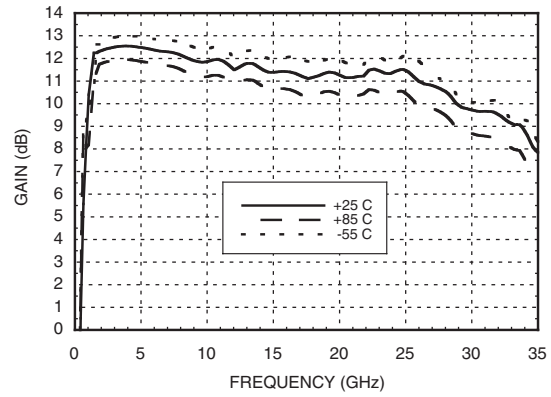


**WIDEBAND DRIVER AMPLIFIER  
MODULE, 2 - 35 GHz**

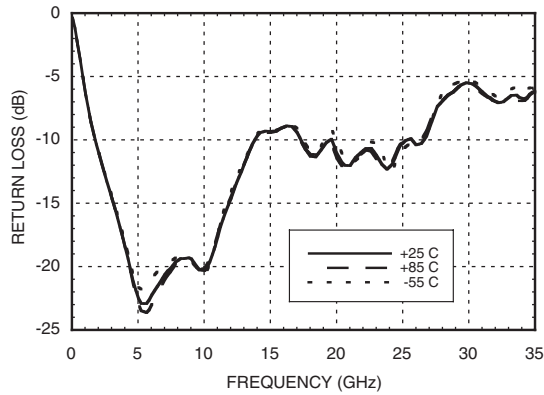
**Gain & Return Loss**



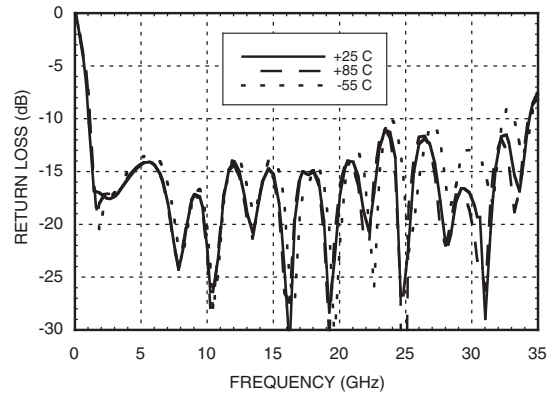
**Gain vs. Temperature**



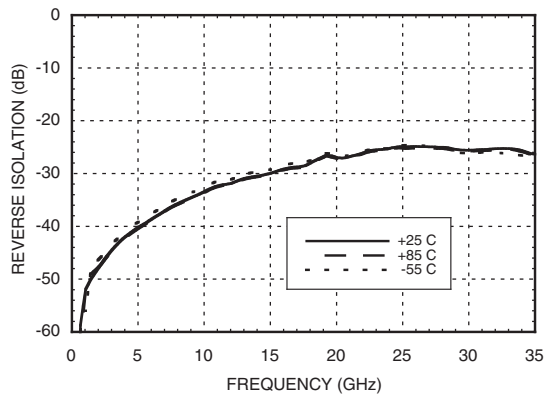
**Input Return Loss vs. Temperature**



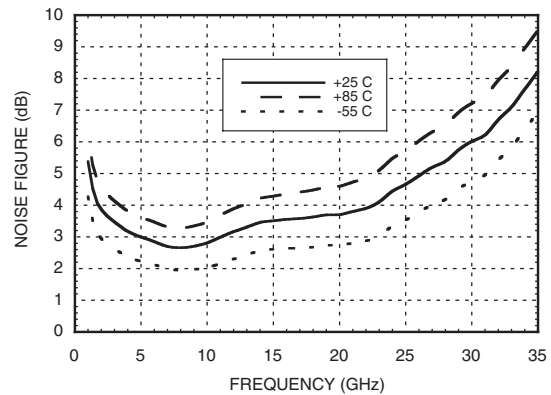
**Output Return Loss vs. Temperature**



**Reverse Isolation vs. Temperature**

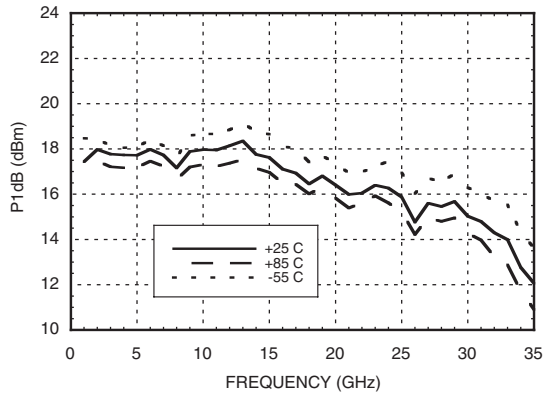


**Noise Figure vs. Temperature**

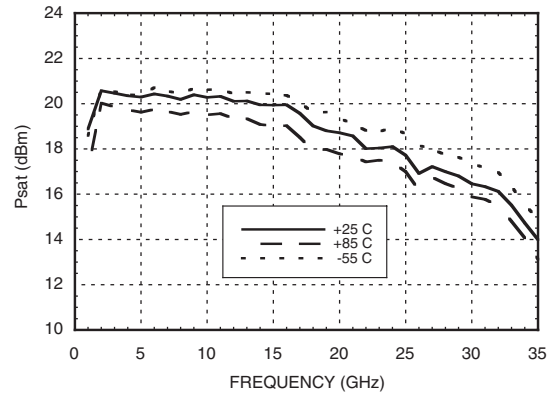


## WIDEBAND DRIVER AMPLIFIER MODULE, 2 - 35 GHz

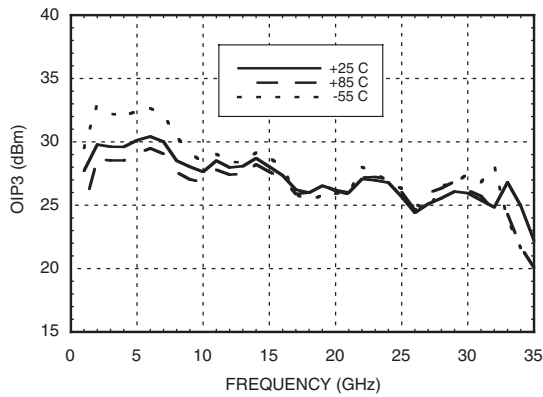
**P1dB vs. Temperature**



**Psat vs. Temperature**



**Output IP3 vs. Temperature**



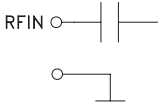

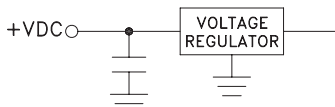
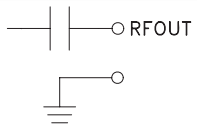
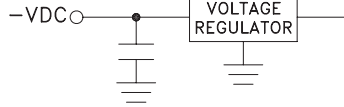
**Absolute Maximum Ratings**

Positive Bias Supply Voltage (+VDC)	+17V Max
Negative Bias Supply (-VDC)	-16V Min.
RF Input Power (RFin)	+23 dBm
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C



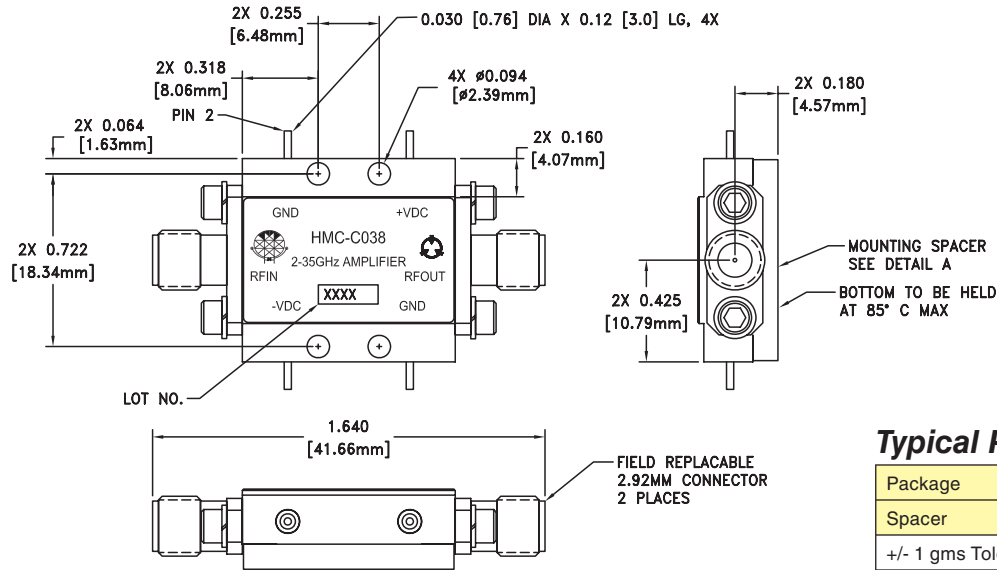
**ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS**

**Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1	RFIN & RF Ground	RF input connector, 2.92 mm female, field replaceable. This pin is AC coupled and matched to 50 Ohms from 2 - 35 GHz.	
2, 5	GND	Power supply ground.	
3	+VDC	Positive power supply voltage for the amplifier.	
4	RFOUT & RF Ground	RF output connector, 2.92 mm female field replaceable. This pin is AC coupled and matched to 50 Ohms from 2 - 35 GHz.	
6	-VDC	Negative power supply voltage for the amplifier	

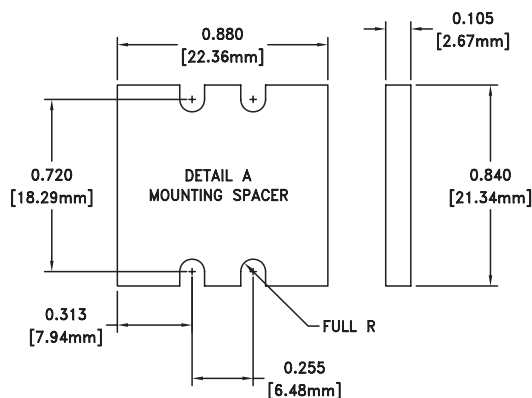
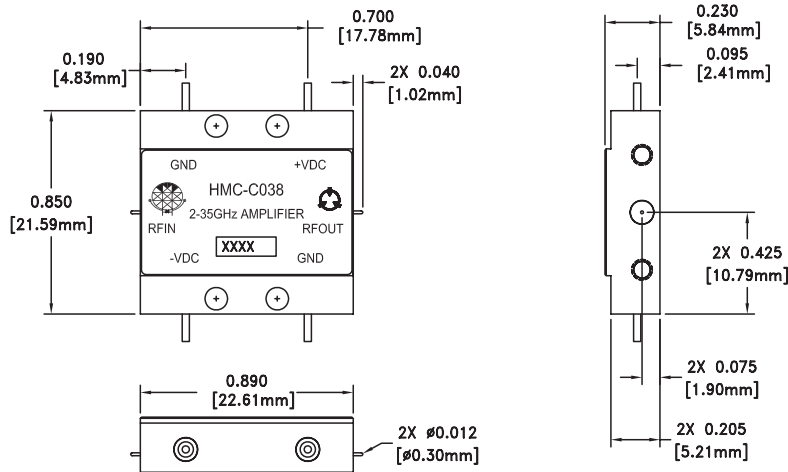
**WIDEBAND DRIVER AMPLIFIER  
MODULE, 2 - 35 GHz**

**Outline Drawing**



**Typical Package Weight**

Package	18.7 gms
Spacer	3.3 gms
+/- 1 gms Tolerance	



- NOTES:
1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
  2. SPACER MATERIAL: ALUMINUM
  3. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 75 MICROINCHES MIN.
  4. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS].
  5. TOLERANCES ±.010 [0.24] UNLESS OTHERWISE SPECIFIED.



v00.0806

**HMC-C038**

**WIDEBAND DRIVER AMPLIFIER  
MODULE, 2 - 35 GHz**

**Notes:**